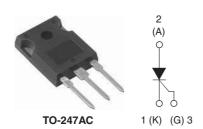


Vishay High Power Products

Phase Control SCR, 35 A



PRODUCT SUMMARY							
V _T at 40 A	< 1.45 V						
I _{TSM}	500 A						
V _{RRM}	1600 V						

DESCRIPTION/FEATURES

The 40TPS16PbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature. Low lgt parts available.



Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

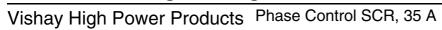
This product has been designed and qualified for industrial level and lead (Pb)-free ("PbF" suffix).

MAJOR RATINGS AND CHARACTERISTICS										
PARAMETER	TEST CONDITIONS	TEST CONDITIONS VALUES								
I _{T(AV)}	Sinusoidal waveform	35	۸							
I _{RMS}		55	Α							
V _{RRM} /V _{DRM}		1600	V							
I _{TSM}		500	А							
V _T	40 A, T _J = 25 °C	1.45	V							
dV/dt		1000	V/µs							
dl/dt		100	A/μs							
TJ		- 40 to 125	°C							

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA
40TPS16PbF	1600	1700	10

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^{*} Pb containing terminations are not RoHS compliant, exemptions may apply





ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average on-state current	I _{T(AV)}	T _C = 79 °C, 180° conduction half sine w	35			
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}		55	Α		
Maximum peak, one-cycle	L	10 ms sine pulse, rated V _{RRM} applied		500		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied		600		
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	Initial $T_J = T_J$ maximum	1250	A ² s	
Maximum 1-t for fusing	ı-ı	10 ms sine pulse, no voltage reapplied	TJIIIAXIIIIAIII	1760	A-5	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied	12 500	A²√s		
Low level value of threshold voltage	V _{T(TO)1}		1.02	V		
High level value of threshold voltage	V _{T(TO)2}	T 105 °C	1.23	V		
Low level value of on-state slope resistance	r _{t1}	T _J = 125 °C		9.74	m()	
High level value of on-state slope resistance	r _{t2}			7.50	mΩ	
Maximum peak on-state voltage	V_{TM}	110 A, T _J = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	dl/dt	T _J = 25 °C		100	A/μs	
Maximum holding current	I _H		150			
Maximum latching current	ΙL			300	A	
Maximum various and divast lacks		T _J = 25 °C	1	0.5	- mA	
Maximum reverse and direct leakage current	I _{RRM} /I _{DRM}	$T_J = 125 ^{\circ}\text{C}$ $V_R = \text{Rated } V_{RRM}/V_{RRM}$	/DRM	10		
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} ,	1000	V/µs		

TRIGGERING						
PARAMETER	SYMBOL	TI	TEST CONDITIONS			
Maximum peak gate power	P_{GM}			10	W	
Maximum average gate power	P _{G(AV)}			2.5	VV	
Maximum peak gate current	I _{GM}			2.5	Α	
Maximum peak negative gate voltage	- V _{GM}			10		
	V _{GT}	T _J = - 40 °C		4.0	V	
Maximum required DC gate voltage to trigger		T _J = 25 °C	Anode supply = 6 V resistive load	2.5		
vollage to ingger		T _J = 125 °C		1.7		
	l _{GT}	T _J = - 40 °C		270		
Maximum required DC acts aureant to trigger		T _J = 25 °C		150	A	
Maximum required DC gate current to trigger		T _J = 125 °C		80	mA	
		T _J = 25 °C, for 40	40			
Maximum DC gate voltage not to trigger	V_{GD}	T = 105 °C V	0.25	V		
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRN}	6	mA		

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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.6				
Maximum thermal resistance, junction to ambient		R_{thJA}		40	°C/W			
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2				
Approximate weight				6	g			
				0.21	OZ.			
Mounting torque	minimum			6 (5)	kgf · cm			
Mounting torque -	maximum			12 (10)	(lbf · in)			
Marking device			Case style TO-247AC	40TF	PS16			

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Vishay High Power Products Phase Control SCR, 35 A



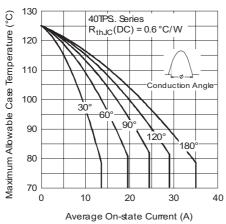


Fig. 1 - Current Rating Characteristics

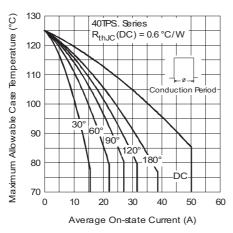


Fig. 2 - Current Rating Characteristics

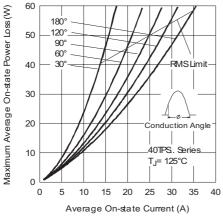


Fig. 3 - On-State Power Loss Characteristics

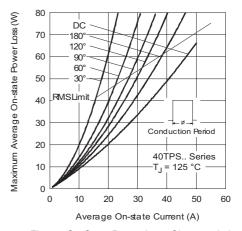


Fig. 4 - On-State Power Loss Characteristics

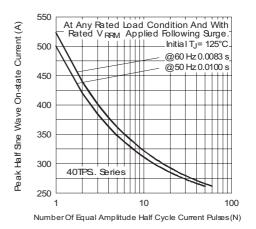


Fig. 5 - Maximum Non-Repetitive Surge Current

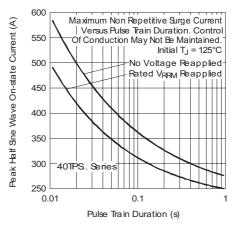


Fig. 6 - Maximum Non-Repetitive Surge Current

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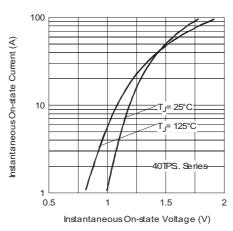


Fig. 7 - On-State Voltage Drop Characteristics

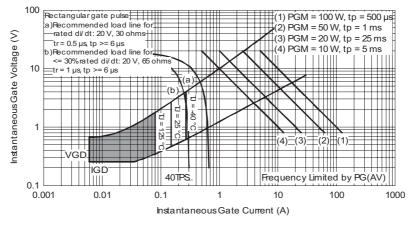


Fig. 8 - Gate Characteristics

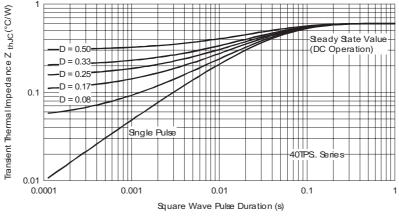


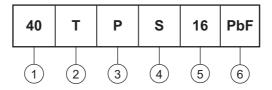
Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

Vishay High Power Products Phase Control SCR, 35 A



ORDERING INFORMATION TABLE

Device code



1 - Current rating (40 = 40 A)

2 - Circuit configuration:

T = Thyristor

- Package:

P = TO-247

4 - Type of silicon:

S = Standard recovery rectifier

5 - Voltage rating (16 = 1600 V)

6 - • None = Standard production

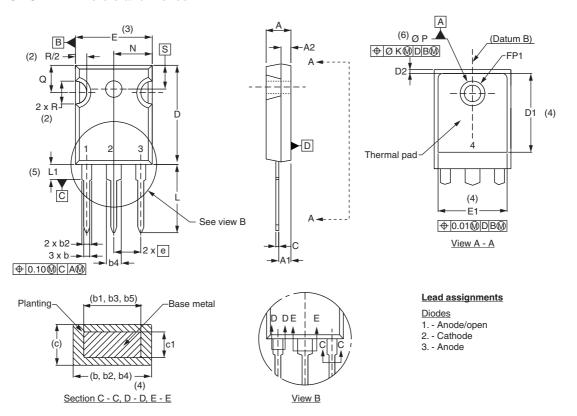
• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS						
Dimensions	http://www.vishay.com/doc?95024					
Part marking information	http://www.vishay.com/doc?95226					



Vishay Semiconductors

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS INCHES		NOTES	NOTES SYMBOL	MILLIN	IETERS	INC	HES	NOTES		
STWIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209			D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098			E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			FK	2.	54	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.37	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133			ΦР	3.56	3.66	0.14	0.144	
С	0.38	0.86	0.015	0.034			ФР1	-	6.98	-	0.275	
c1	0.38	0.76	0.015	0.030			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	1.78	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	'BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c

Legal Disclaimer Notice



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